Diode Semiconductor Device - Page 1 of 1



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	losure Material:
Gla	
	erall Length:
	50 inches
	rminal Length:
	00 inches
	erall Diameter:
	85 inches
	nction For Which Designed:
	ner diode
	unting Method:
	minal
	atures Provided:
	rmetically sealed case
	miconductor Material:
	con
	Itage Rating In Volts Per Characteristic:
	0 regulator voltage
Vo	Itage Tolerance In Percent:
-5.0	0/+5.0
Cu	rrent Rating Per Characteristic:
30.	00 milliamperes all primaries horsepower metric
Po	wer Rating Per Characteristic:
3.0	watts small-signal input power, common-collector preset
Ма	ximum Operating Tempurature Per Measurement Point:
175	5.0 degrees celsius junction
Ter	minal Type And Quantity:
2 u	ninsulated wire lead
Sh	elf Life:
N/a	ì
	it Of Measure:
 De	militarization:
No	
Fiig	g:
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